

## Wet Bench Training

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## Wet Bench Training

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## Wet Bench Training

### Safety Equipment

#### *Required Apparel...*

- Safety Glasses
- Long Pants
- Full Shoes, Leather Recommended  
(No Sandals!)

#### *To Be Used Whenever Processing Chemicals...*

- Vinyl Apron
- Face Shield
- Trionic Gloves

## Wet Bench Training

### Lab Supplies

#### *In Cabinets #1 and #39 by Gowning Area...*

- Hazardous Waste Jugs
- Cleanroom Wipes
- Vinyl Aprons
- Face Shields
- Trionic Gloves
- Many Other Supplies

*These items are usually stocked on the wire racks near the wet benches – but can be replenished from these cabinets at any time.*

## Wet Bench Training

### Hazardous Waste Disposal

#### *Hazardous Waste Jugs...*

- Name, Date, Contents, Ratios
- Leave cap slightly loose with  $H_2O_2$

#### *In-Sink Acid Disposal...*

- See "Acid Draining Procedure" posted at benches with permanent acid tanks.
- See "Flushing Acids in Bay 1 & Bay3" at benches for list of acceptable acids. In general, all clear acids except HCL.

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### Hazardous Waste Carts

- Located by gowning area
- Top of Cart – Hazardous Waste Jugs
- Bottom of Cart – Empty Chemical Containers; rinse 3X with water and mark with an "X" on bottle and cap before placing on cart.

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### Waste Receptacles

- Receptacles labeled "Trash Only – No Hazardous Materials" are regular trash. It is acceptable to put acid and base wipes in them, but wipes must be rinsed with DI water prior to disposal.
- Solvent Wipes – collected as hazardous waste. For solvent wipes only.
- Photoresist Wipes – collected as hazardous waste. For wipes with photoresist on them.
- Broken Wafer and Glass – regular trash. Any 'sharp' that is chemically inert may be placed here.

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### Chemical Baths / Beakers

- Heated Chemical Bath Controller – press "Power"• to turn on controller. Press "Hold"• to take off hold and actively heat the bath. Heat LED will light when heat is being applied.
- Beakers – Use labels located on wire racks. Name, Date, Contents, Ratios. No need to label lid.




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### Rinse Baths

- DI Rinse Bath Controller – Press "Start"• to begin 3 cycle rinse. Note, it may be necessary to press "Stop/Reset"• once prior to pressing "Start" to initiate the cycle. To drain water manually, press "Open"•.



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### Chemical Storage

<b>BAY 1:</b> Oxidizer Cabinet Base Cabinet Acid Cabinet	<b>BAY 3:</b> Oxidizer Cabinet Base Cabinet Acid Cabinet "wb-etch" Cupboards	<b>AREA 1:</b> Hazardous Waste Cabinet
<b>BAY 2:</b> Flammable Cabinet Fume Hood Cupboards "wb-resist" Cupboards "wb-solvents" Tray	<b>BAY 4:</b> "wb-koh" Drawers "wb-maskmaking" Cupboards	<b>AREA 2:</b> Flammable Cabinet Acid Cabinet
		<b>CHASE 4:</b> Flammable Cabinets 1-3 Base Cabinet 1 Acid Cabinets 1-2 Oxidizer Cabinet

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### Chemical Inventory

<b>ACIDS:</b> Acetic Acid Ammonium Fluoride Buffered Oxide Etch 10:1 Fuming Chloride Fluoroboric Acid Hydrochloric Acid Hydrofluoric Acid (48%) Nitric Acid Phosphoric Acid Sulfuric Acid	<b>ORGANIC SOLVENTS:</b> Acetone Dichloromethane Chlorobenzene Isopropanol Methanol N-methyl-2-pyrrolidone Standard solvent Toluene Trichloroethylene	<b>POSITIVE PHOTORESISTS:</b> <b>THICK:</b> Shipley's 1945 Shipley's 1975 AZ's 9260 <b>NEGATIVE PHOTORESIST:</b> <b>THIN:</b> Futura	<b>PHOTORESIST STRIPPERS:</b> J.T. Baker's PRS-1000 (for positive PR) Shipley's 1165 (for PMG)
<b>BASES:</b> Ammonium Hydroxide Potassium Hydroxide	<b>PHOTORESIST PRIMER:</b> HMDS	<b>IMAGE REVERSAL PHOTORESIST:</b> AZ's 9214	<b>METAL ETCHANTS:</b> <b>PRE-MIXED:</b> J.T. Baker Al Etchant Cyantek CR-125 Cr Etchant Acton GE-4 Au Etchant
<b>Oxidizers:</b> Hydrogen Peroxide	<b>POSITIVE PHOTORESISTS:</b> <b>THIN:</b> Shipley's 1805 Shipley's 1813 Shipley's 1815	<b>PHOTORESIST DEVELOPERS:</b> Shipley's 351 Shipley's MP-310 Shipley's MP-CD-28 AZ's 400K 1-Methoxy-2-propanol ("PM Acetone" for SU-8)	

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### Bay Designations

- Bay 1 – No metal processing in the wet benches or with the wafer handling equipment. No PECVD films, Pyrex glass, or KOH contaminated wafers.
- Bay 2 – No acids whatsoever. Processing in this bay is limited to solvents, polymers, and mild bases in the form of developers.
- Bay 3 – Primarily acid etching of metals. Metal, PECVD, Pyrex, and KOH processing okay here.
- Bay 4 – Primarily KOH etching of silicon, electroplating of PR, and staff-only mask processing.

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### Wet Bench Designations

<b>BAY 1:</b> wb-hf wb-rca wb-gen-1 srd-2  <b>CHASE 1:</b> srd-1  <b>BAY 2:</b> wb-resist wb-sol srd-3	<b>BAY 3:</b> wb-etch unnamed srd  <b>BAY 4:</b> wb-koh wb-maskmaking	<b>AREA 1:</b> wb-maint  <b>AREA 2:</b> wb-gen-2 srd-4
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**Note 1:** These are the Coral names. They have been used to save space and to familiarize users with their proper names.

**Note 2:** "wb" = Wet Bench  
"srd" = Spin Rinsing Dryer

**Note 3:** At this time there is no charge associated with any of the wb's or srd's in the lab. They do not need to be enabled in Coral to be operated. All users who have received Wet Bench training are qualified under the category "wb-hf".

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### RCA Clean Process

(see wb-rca for more specific instructions)  
(you will need to be shown the NH<sub>4</sub>OH aspirator)

**STEP 1:**  
removal of residual organic contaminants – 80 °C, 15 min followed by DI rinse  
H<sub>2</sub>O : NH<sub>4</sub>OH : H<sub>2</sub>O<sub>2</sub>    5 : 1 : 1    (3200 ml : 640 ml : 640 ml)

**STEP 2:**  
removal of hydrous oxide formed during step 1 – room temp, 15 sec. followed by DI rinse  
H<sub>2</sub>O : HF    10 : 1    (5500 ml : 550 ml)

**STEP 3:**  
desorption of remaining ionic contaminants – 80 °C, 15 min followed by DI rinse  
H<sub>2</sub>O : HCL : H<sub>2</sub>O<sub>2</sub>    6 : 1 : 1    (3360 ml : 560 ml : 560 ml)

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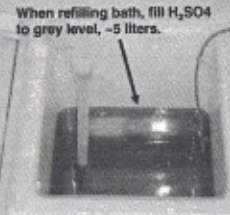
### 'Piranha' Clean Process

'Piranha' clean consists of 10 parts H<sub>2</sub>SO<sub>4</sub> to 1 part H<sub>2</sub>O<sub>2</sub>. When the bath is re-used, the 1 part H<sub>2</sub>O<sub>2</sub> is added again to the bath.

This is referred to as 'spiking' the bath. Spike the bath with about 500 ml H<sub>2</sub>O<sub>2</sub>.

- The set point of the bath is 120 °C. A new mixture won't require any heating.
- Typical clean time is 10 min.

When refilling bath, fill H<sub>2</sub>SO<sub>4</sub> to grey level, ~5 liters.



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### KOH Si Etching Process

(see wb-koh for more specific information on etch rate as a function of temp. and concentration)  
(You will need to be shown how to drain the KOH bath into the 5 gal. Haz. Waste Jug in Chase 3.)

- A typical etch process might consist of a 45% KOH solution @ 80 °C with an etch rate of 55 µm/hour.
- For faster etch rates, 80 to 140 µm/hour, a 20 to 25% solution may be used from 80 to 90 °C.
- 'Out of the Bottle' KOH is at a 45% concentration.
- Only the bath on the right of the bench is for General Use. Change bath label to note Name, Date, Contents, Concentration.

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## Wet Bench Training

### Aqua Regia Process

- Aqua Regia (HCL and Nitric Acid mixtures) should only be performed in Bay 3's Etch Wet Bench in a Pyrex beaker on top of a hot plate. Place the beaker on the right-hand side of the wet bench and close the two right-most sashes to contain the fumes.
- Aqua regia emits chlorine gas. It is important to keep this contained within the wet bench to avoid harmful exposure to the gas, and to prevent avoidable lab evacuations.